

# IN3170 V24 - Lab 3

Andreas Engøy, Simen Norrud, Erik Røset & Daniel Tran

April 2024

## 1 Task 1

### 1.1 Equipment

Component	Model	Quantity
Resistor	100k $\Omega$	1

Table 1: List of components used in task 1.

## 2 Task 2

In an ideal current source, the output current is independent of the voltage across the terminals. I.e. the current source maintains the same current through the circuit, despite changes to  $V_{DS}$ .

A Field-Effect Transistor (FET) operation in the saturation region exhibits the same characteristics as an ideal current source. This can be seen from the  $I_D$  vs  $V_{DS}$  curve in the saturation region, where the current is almost constant. This is because  $V_{DS}$  approaching the saturation region is high enough that it has maxed out the number of charge carriers that can contribute to current flow, making the gate voltage the primary factor to the current flow.

In the plot, the curve will flatten out in this region. In a practical FET, the curve will not be completely flat (indicating that the current is not completely constant), but it will give a good approximation of an ideal current source.

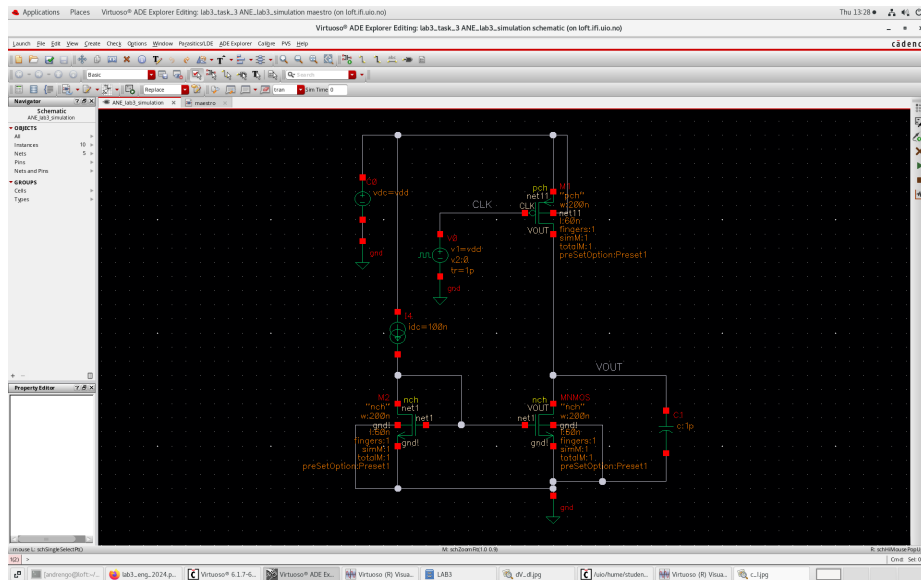


Figure 1: Screenshot of the circuit in figure 1 c) from the lab manual simulated in Cadence.